

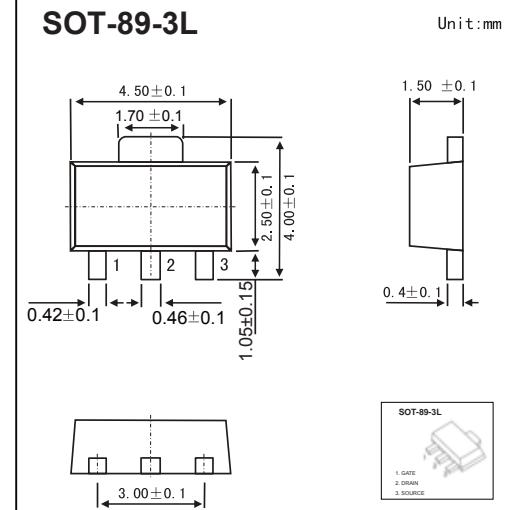
SOT-89-3L Plastic-Encapsulate MOSFETS

FEATURE

- N-Channel 20-V(D-S) MOSFET

MECHANICAL DATA

- Case style:SOT-89-3L molded plastic
- Mounting position:any



MAXIMUM RATINGS AND CHARACTERISTICS

@ 25°C Ambient Temperature (unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V _{DS}	20	V
Continuous Gate-Source Voltage	V _{GS}	±12	
Continuous Drain Current	I _D	4	A
Power Dissipation	P _D	0.5	W
Thermal Resistance from Junction to Ambient	R _{θJA}	250	°C/W
Operating Temperature	T _j	150	°C
Storage Temperature	T _{stg}	-55 ~+150	

V _{(BR)DSS}	R _{DS(on)MAX}	I _D
20V	38mΩ@10V	4A
	50mΩ@4.5V	
	80mΩ@2.5V	

MOSFET ELECTRICAL CHARACTERISTICS $T_A=25^\circ C$ unless otherwise specified

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Off characteristics						
Drain-source breakdown voltage	$V_{(BR)DSS}$	$V_{GS} = 0V, I_D = 250\mu A$	20			V
Gate-body leakage	I_{GSS}	$V_{DS} = 0V, V_{GS} = \pm 12V$			± 100	nA
Zero gate voltage drain current	I_{DSS}	$V_{DS} = 20V, V_{GS} = 0V$			1.0	μA
On characteristics						
Gate-threshold voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = 0.25mA$	0.70		1.50	V
Static drain-source on-resistance (note 1)	$R_{DS(on)}$	$V_{GS} = 10V, I_D = 4A$			0.038	Ω
		$V_{GS} = 4.5V, I_D = 4A$			0.05	
		$V_{GS} = 2.5V, I_D = 3A$			0.08	
Forward transconductance (note 1)	g_{fs}	$V_{DS} = 5V, I_D = 3A$	3			S
Dynamic characteristics (note 2)						
Input capacitance	C_{iss}	$V_{DS} = 20V, V_{GS} = 0V, f = 1MHz$			570	pF
Output capacitance	C_{oss}			80		
Reverse transfer capacitance	C_{rss}			65		
Switching characteristics						
Turn-on delay time (note 1,2)	$t_{d(on)}$	$V_{GS} = 5V, V_{DS} = 10V, I_D = 1A, R_{GEN} = 3.3\Omega, R_D = 10\Omega$		8		ns
Rise time (note 2)	t_r			9		
Turn-off delay time (note 2)	$t_{d(off)}$			13		
Fall time (note 2)	t_f			3		
Drain-source body diode characteristics						
Body diode forward voltage (note 1)	V_{SD}	$I_S = 1A, V_{GS} = 0V$			1.3	V

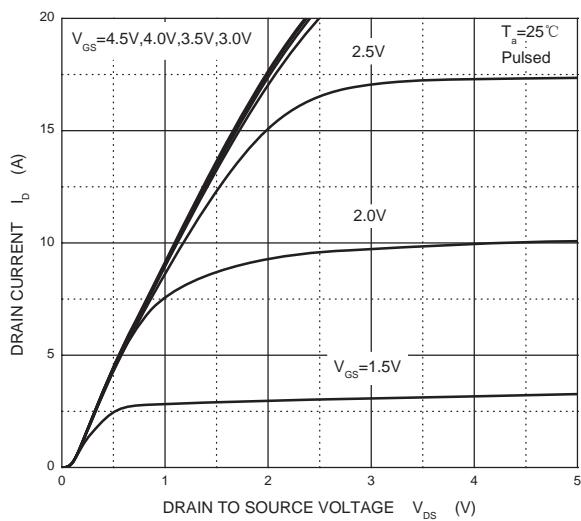
No tes:

1. Pulse Test ; Pulse Width $\leq 300\mu s$, Duty Cycle $\leq 2\%$.
2. These parameters have no way to verify.

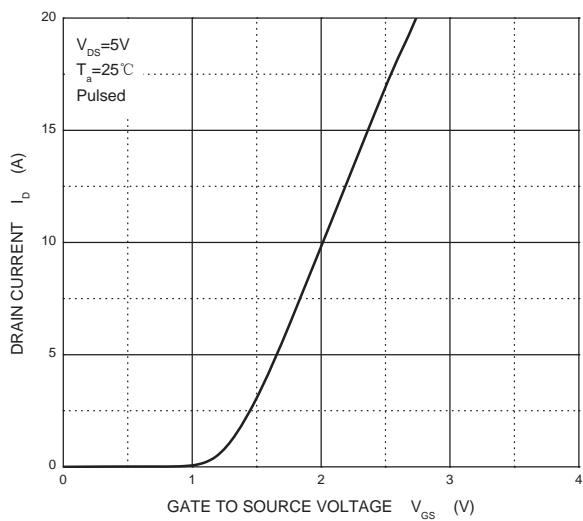
RATINGS AND CHARACTERISTIC CURVES

■ Typical Characteristics

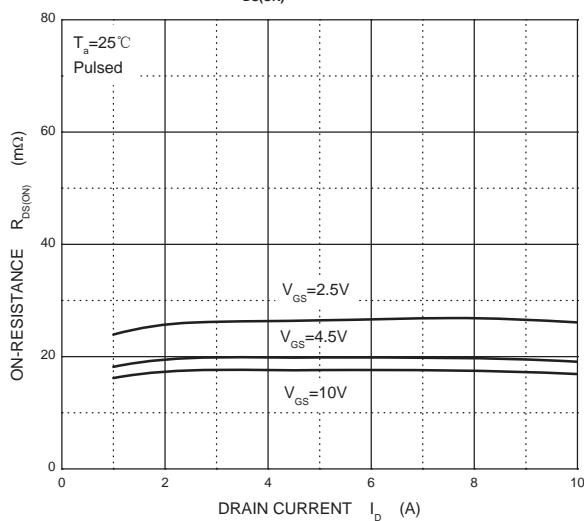
Output Characteristics



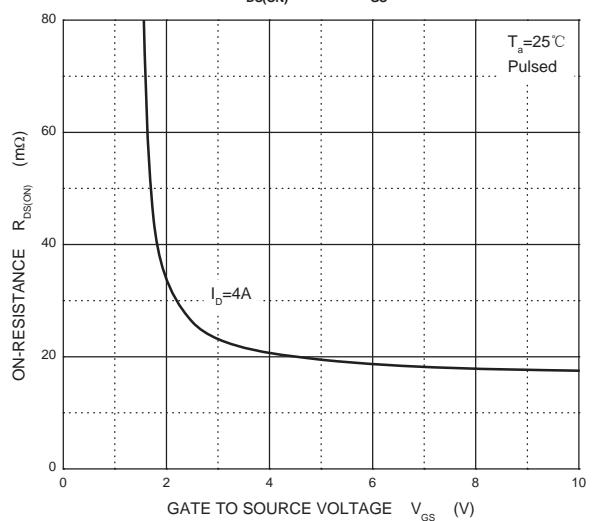
Transfer Characteristics



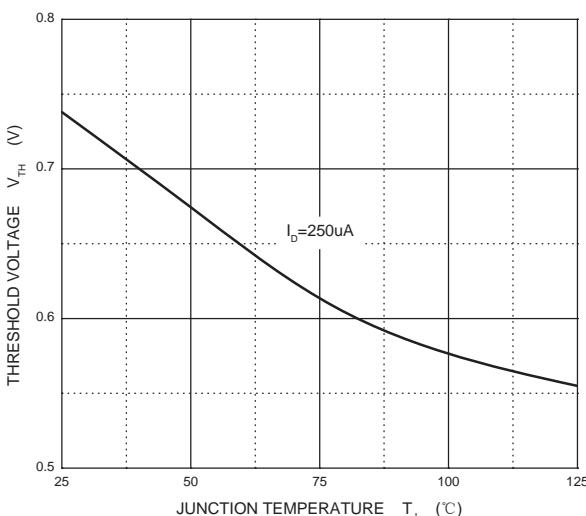
$R_{DS(ON)}$ — I_D



$R_{DS(ON)}$ — V_{GS}



Threshold Voltage



I_s — V_{SD}

